
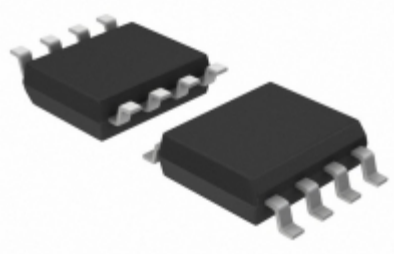

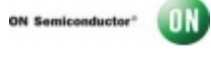
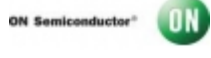

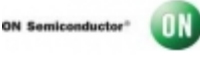



	<h2 style="color: red;">NTMS4802NR2G</h2>
	<p>Hersteller-Teilenummer: NTMS4802NR2G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 11.1A 8-SOIC</p> <hr/> <p>Datenblätter:  NTMS4802NR2G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 35783 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMS4802NR2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 11.1A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35783 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	910mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11.1A (Ta)
Rds On (Max) @ Id, Vgs	4 mOhm @ 18A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	36nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	5300pF @ 25V
Verpackung	Tape & Reel (TR)
























NTMS4802NR2G ist neu im Original, Suche NTMS4802NR2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMS4802NR2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMS4802NR2G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMS4801NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.5A 8-SOIC</p>	 <p>NTMS4801N AMI Semiconductor / ON Semiconductor NTMS4801N ON</p>	 <p>NTMS4807N AMI Semiconductor / ON Semiconductor NTMS4807N ON</p>	 <p>NTMS4816NG ON NTMS4816NG ON</p>
 <p>NTMS4802N AMI Semiconductor / ON Semiconductor NTMS4802N ON</p>	 <p>NTMS4800N ON NTMS4800N ON</p>	 <p>NTMS4800NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 4.9A 8-SOIC</p>	 <p>NTMS4807NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.1A 8-SOIC</p>

heiße Teile

Mehr

 NTMFS5C628NLT1G	 NTMFS5C646NLT1G	 NTMFS5C670NLT1G	D NTMS10P02	 NTMS10P02R2
 NTMS10P02R2G	 NTMS3P03R2	D NTMS3P03R2G	 NTMS4101PR2G	 NTMS4105NR2G
 NTMS4107NR2G	 NTMS4176PR2G	 NTMS4177P	 NTMS4177PR2G	 NTMS4404NR2G
D NTMS4503NR2G	 NTMS4700NR	 NTMS4700NR2G	 NTMS4704NR2G	 NTMS4705NR2G
 NTMS4706NR2G	 NTMS4800NR2G	 NTMS4801N	 NTMS4801NR2G	 NTMS4802N
 NTMS4807N	 NTMS4807NR2G	D NTMS4816N	 NTMS4816NG	 NTMS4816NR2G
 NTMS4840NR2G	D NTMS4872NR2G	 NTMS4873NFR2G	 NTMS4916AS001	 NTMS4916N
 NTMS4916NR2G	 NTMS4916UT001	 NTMS4917NR2G	 NTMS4917UT001	 NTMS4920N
 NTMS4920NR2G	 NTMS4937N	 NTMS4937NR2G	D NTMS4939N	 NTMS4939NR2G
 NTMS4N01R2	 NTMS4P01R2G	 NTMS5835NL	 NTMS5835NLR2G	 NTMS5838NLR2G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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